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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In repatent application of

Noboru ICHINOSE, et al.

Serial No.:

10/589,852

Group Art Unit:

Unknown

Filed:

August 17, 006

Examiner:

Unknown

For:

METHOD FOR CONTROLLING CONDUCTIVITY OF Ga<sub>2</sub>O<sub>3</sub>

SINGLE CRYSTAL

Honorable Commissioner of Patents Alexandria, Virginia 22313-1450

## INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.98 and pursuant to Applicant's duty of disclosure under 37 CFR §1.56, Applicant respectfully brings the following documents cited in the International Search Report in a counterpart foreign application and listed on the attached form PTO-1449, to the attention of the Examiner in charge of the above-identified application. Copies of the listed U.S. Patent Application Publication are not provided in compliance with *Information Disclosure Statements May Be Filed Without Copies of U.S. Patents and Published Applications in Patent Applications filed after June 30, 2003*, 1273 Off. Gaz. Pat. Office 55 (August 5, 2003). For the convenience of the Examiner, copies of the first page of the listed U.S. Patent Application Publication are provided.

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which Applicant is aware.

In compliance with the concise explanation requirement under 37 CFR §1.98(a)(3) for foreign language documents, Applicant encloses herewith a copy of the International Search

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Serial No.:

10/589,852

Docket No.:

PKHF-05004US

HIR.228

Report citing such documents, together with an English-language version (if not already included) of that portion of the Search Report indicating the degree of relevance found by the foreign office.

Please charge any deficiencies in fees and credit any overpayment of fees to Attorney's Deposit Account No. 50-0481.

Respectfully submitted,

Sean M. McGinn, Esq. Registration No. 34,386

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Customer No. 21254

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